NSN 5961-01-004-1058

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breakdown voltage, collector-to-emitter, base open and 4.0 breakdown

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V	iew Online at https://aerobasegroup.com/nsn/5961-01-004-1058
In	nclosure Material:
Ρ	lastic
0	verall Length:
).	190 inches
Γ	erminal Length:
).	500 inches
C	verall Height:
).	165 inches
n	ternal Configuration:
l	unction contact
Ξ	lectrode Internally-electrically Connected To Case:
)	ollector
Λ	lounting Method:
Ī	erminal
3	emiconductor Material:
S	ilicon
/	oltage Rating In Volts Per Characteristic:
ļ	5.0 breakdown voltage, collector-to-base, emitter open and 45.0
(oltage, emitter-to-base, collector open
;	urrent Rating Per Characteristic:
(0.00 milliamperes source cutoff current
)	ower Rating Per Characteristic:
(00.0 milliwatts small-signal input power, common-collector
-	ransfer Ratio:
4	0.0 static forward current transfer ratio, common-emitter
M	aximum Operating Tempurature Per Measurement Point:
(65.0 degrees celsius junction
3	pecial Features:
Jı	unction pattern arrangement: npn
Г	erminal Type And Quantity:
3	uninsulated wire lead
s	helf Life:
N	/a
U	nit Of Measure:
D	emilitarization:
N	0
E	lig: